

## Refine Search

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L6 AND (IMPLANT\$3 WITH THICKNESS)	421

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### Search History

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<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=OR</i>			
<u>L7</u>	L6 AND (IMPLANT\$3 WITH THICKNESS)	421	<u>L7</u>
<u>L6</u>	L5 AND (WELL OR N-WELL OR P-WELL OR TUB)	2611	<u>L6</u>
<u>L5</u>	L4 AND IMPLANT\$5	3022	<u>L5</u>
<u>L4</u>	L3 AND (DRAIN WITH RESISTANCE)	4042	<u>L4</u>
<u>L3</u>	L2 AND VOLTAGE	11686	<u>L3</u>
<u>L2</u>	(DRAIN WITH (EXTEND\$3 OR EXTENSION)) AND (MOS OR MOSFET)	17386	<u>L2</u>
<u>L1</u>	(DRAIN WITH EXTEN\$6) AND (MOS OR MOSFET)	12867	<u>L1</u>

END OF SEARCH HISTORY